SGS-THOMSON MICROELECTRONICS

M54HC238
M74HC238

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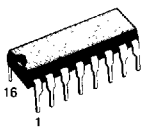
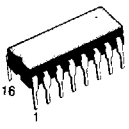
T-67-21-55

3 TO 8 LINE DECODER

- HIGH SPEED
  t_{PD} = 18 ns (TYP.) at V_{CC} = 5V
- LOW POWER DISSIPATION
  I_{CC} = 4 μA (MAX.) at T_A = 25°C
- HIGH NOISE IMMUNITY
  $V_{NIH} = V_{NIL}$ = 28% V_{CC} (MIN.)
- OUTPUT DRIVE CAPABILITY
  10 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE
  $|I_{OH}| = I_{OL}$ = 4 mA (MIN.)
- BALANCED PROPAGATION DELAYS
  $t_{PLH} = t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE
  V_{CC} (OPR) = 2V to 6V
- PIN AND FUNCTION COMPATIBLE
  WITH 54/74LS238



B1
Plastic Package



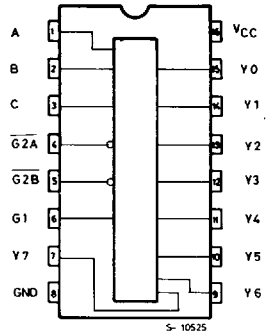
F1
Ceramic Frit Seal Package

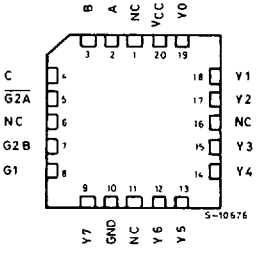
M1
Micro Package

C1
Plastic Chip Carrier

ORDERING NUMBERS:
M54HC238 F1
M74HC238 B1N
M74HC238 F1
M74HC238 M1

PIN CONNECTIONS (top view)





NC = No Internal Connection

DESCRIPTION

The M54/74HC238 is a high speed CMOS 3 to 8 line decoder fabricated in silicon gate C²MOS technology. It has the same high speed performance of LSTTL combined with true CMOS low power consumption. If the device is enabled, 3 binary select inputs (A, B and C) determine which one of outputs will go high. Enable input G1 is held "Low" or either G2A or G2B is held "High" decoding function is inhibited and all the 8 outputs go low. Three enable inputs are provided to ease cascade connection and application of this address decoder in memory systems.
All inputs are equipped with protection circuits against static discharge and transient excess voltage.

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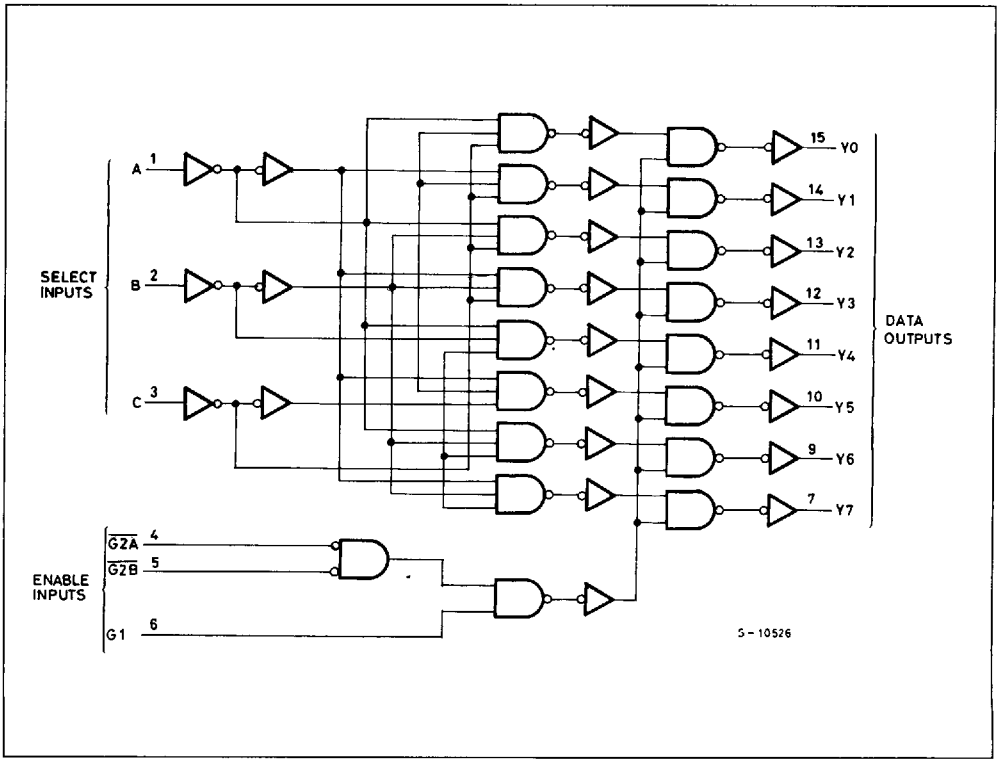
TRUTH TABLE

INPUTS						OUTPUTS								SELECTED OUTPUT
ENABLE			SELECT											
$\overline{G2B}$	$\overline{G2A}$	G1	C	B	A	Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7	
X	X	L	X	X	X	L	L	L	L	L	L	L	L	NONE
X	H	X	X	X	X	L	L	L	L	L	L	L	L	NONE
H	X	X	X	X	X	L	L	L	L	L	L	L	L	NONE
L	L	H	L	L	L	H	L	L	L	L	L	L	L	Y0
L	L	H	L	L	H	L	H	L	L	L	L	L	L	Y1
L	L	H	L	H	L	L	L	H	L	L	L	L	L	Y2
L	L	H	L	H	H	L	L	L	H	L	L	L	L	Y3
L	L	H	H	L	L	L	L	L	L	H	L	L	L	Y4
L	L	H	H	L	H	L	L	L	L	L	H	L	L	Y5
L	L	H	H	H	L	L	L	L	L	L	L	H	L	Y6
L	L	H	H	H	H	L	L	L	L	L	L	L	H	Y7

X: = DON'T CARE

LOGIC DIAGRAM



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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	−0.5 to 7	V
V_I	DC Input Voltage	−0.5 to V_{CC} + 0.5	V
V_O	DC Output Voltage	−0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Source Sink Current Per Output Pin	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	500 (*)	mW
T_{stg}	Storage Temperature	−65 to 150	°C

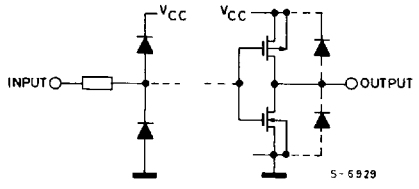
Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(*) 500 mW = 65°C derate to 300 mW by 10 mW/°C: 65°C to 85°C.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value		Unit
V_{CC}	Supply Voltage	2 to 6		V
V_I	Input Voltage	0 to V_{CC}		V
V_O	Output Voltage	0 to V_{CC}		V
T_A	Operating Temperature 74HC Series Operating Temperature 54HC Series	−40 to 85 −55 to 125		°C
t_r, t_f	Input Rise and Fall Time	V_{CC} = 2 V	0 to 1000	ns
		V_{CC} = 4.5V	0 to 500	
		V_{CC} = 6 V	0 to 400	

INPUT AND OUTPUT EQUIVALENT CIRCUIT



DC SPECIFICATIONS

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Symbol	Parameter	V_{CC}	Test Condition		$T_A = 25°C$ 54HC and 74HC			−40 to 85°C 74HC		−55 to 125°C 54HC		Unit
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V_{IH}	High Level Input Voltage	2.0			1.5	—	—	1.5	—	1.5	—	V
		4.5			3.15	—	—	3.15	—	3.15	—	
		6.0			4.2	—	—	4.2	—	4.2	—	
V_{IL}	Low Level Input Voltage	2.0			—	—	0.5	—	0.5	—	0.5	V
		4.5			—	—	1.35	—	1.35	—	1.35	
		6.0			—	—	1.8	—	1.8	—	1.8	
V_{OH}	High Level Output Voltage	2.0	V_I	I_O	1.9	2.0	—	1.9	—	1.9	—	V
		4.5	V_{IH} or V_{IL}	−20 μA	4.4	4.5	—	4.4	—	4.4	—	
		6.0			5.9	6.0	—	5.9	—	5.9	—	
		4.5		−4.0 mA	4.18	4.31	—	4.13	—	4.10	—	
		6.0		−5.2 mA	5.68	5.8	—	5.63	—	5.60	—	
V_{OL}	Low Level Output Voltage	2.0	V_{IH} or V_{IL}	20 μA	—	0.0	0.1	—	0.1	—	0.1	V
		4.5			—	0.0	0.1	—	0.1	—	0.1	
		6.0			—	0.0	0.1	—	0.1	—	0.1	
		4.5		4.0 mA	—	0.17	0.26	—	0.33	—	0.40	
		6.0		5.2 mA	—	0.18	0.26	—	0.33	—	0.40	
I_I	Input Leakage Current	6.0	$V_I = V_{CC}$ or GND		—	—	±0.1	—	±1.0	—	±1.0	μA
I_{CC}	Quiescent Supply Current	6.0	$V_I = V_{CC}$ or GND		—	—	4	—	40	—	80	μA

AC ELECTRICAL CHARACTERISTICS ($V_{CC} = 5V$, $T_A = 25°C$, $C_L = 15pF$, Input $t_r = t_f = 6ns$)

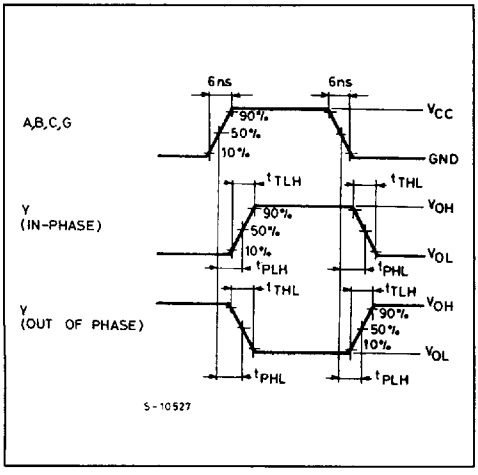
Symbol	Parameter	54HC and 74HC			Unit
		Min.	Typ.	Max.	
t_{TLH} t_{THL}	Output Transition Time		4	8	ns
t_{PLH} t_{PHL}	Propagation Delay Time (A,B,C-Y)		18	28	ns
t_{PLH} t_{PHL}	Propagation Delay Time (G1-Y)		17	27	ns
t_{PLH} t_{PHL}	Propagation delay Time ($\overline{G2}$-Y)		19	29	ns

AC ELECTRICAL CHARACTERISTICS (C_L = 50pF, Input $t_r = t_f$ = 6ns)

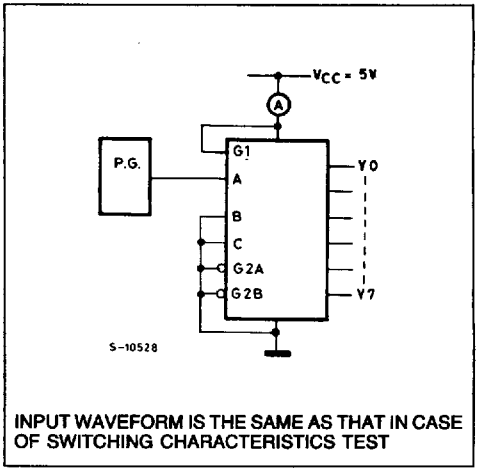
Symbol	Parameter	V_{CC}	Test Condition	T_A = 25°C 54HC and 74HC			−40 to 85°C 74HC		−55 to 125°C 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t_{TLH} t_{THL}	Output Transition Time	2.0		—	30	75	—	95	—	110	ns
		4.5		—	8	15	—	19	—	22	
		6.0		—	7	13	—	16	—	19	
t_{PLH} t_{PHL}	Propagation Delay Time (A,B,C-Y)	2.0		—	84	165	—	205	—	250	ns
		4.5		—	21	33	—	41	—	50	
		6.0		—	18	28	—	35	—	43	
t_{PLH} t_{PHL}	Propagation Delay Time (G1-Y)	2.0		—	80	155	—	195	—	235	ns
		4.5		—	20	31	—	39	—	47	
		6.0		—	17	26	—	33	—	40	
t_{PLH} t_{PHL}	Propagation Delay Time ($\overline{G2}$-Y)	2.0		—	88	170	—	215	—	255	ns
		4.5		—	22	34	—	43	—	51	
		6.0		—	19	29	—	37	—	43	
C_{IN}	Input Capacitance			—	5	10	—	10	—	10	pF
C_{PD} (*)	Power Dissipation Capacitance			—	67	—	—	—	—	—	pF

Note (*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit)
Average operating current can be obtained from the equation: I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

SWITCHING CHARACTERISTICS TEST WAVEFORM



TEST CIRCUIT I_{CC} (Opr.)



INPUT WAVEFORM IS THE SAME AS THAT IN CASE OF SWITCHING CHARACTERISTICS TEST